

# Operational Amplifier, Rail-to-Rail Output, 3 MHz BW

## TLV271, TLV272, NCV272, TLV274, NCV274

The TLV/NCV27x operational amplifiers provide rail-to-rail output operation. The output can swing within 320 mV to the positive rail and 50 mV to the negative rail. This rail-to-rail operation enables the user to make optimal use of the entire supply voltage range while taking advantage of 3 MHz bandwidth. The opamp can operate on supply voltage as low as 2.7 V over the temperature range of  $-40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ . The high bandwidth provides a slew rate of  $2.4\text{ V}/\mu\text{s}$  while only consuming  $550\text{ }\mu\text{A}$  of quiescent current. Likewise the opamp can run on a supply voltage as high as 16 V (single) and 36 V (dual quad) making it ideal for a broad range of battery-operated applications. Since this is a CMOS device it has high input impedance and low bias currents making it ideal for interfacing to a wide variety of signal sensors. In addition it comes in a variety of compact packages with different pinout styles allowing for use in high-density PCB's.

### Features

- Rail-To-Rail Output
- Wide Bandwidth: 3 MHz
- High Slew Rate:  $2.4\text{ V}/\mu\text{s}$
- Wide Power-Supply Range: 2.7 V to 16 V (TLV271), 36 V (TLV/NCV272/274)
- Low Supply Current:  $550\text{ }\mu\text{A}$
- Low Input Bias Current:  $45\text{ pA}$
- Wide Temperature Range:  $-40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$
- TSOP-5, Micro-8, SOIC-8, SOIC-14, TSSOP-14 Packages
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

### Applications

- Notebook Computers
- Portable Instruments
- Signal Conditioning
- Automotive
- Power Supplies
- Current Sensing

This document contains information on some products that are still under development. ON Semiconductor reserves the right to change or discontinue these products without notice.



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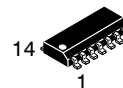
TSOP-5  
CASE 483



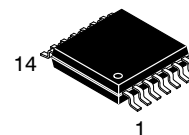
Micro8™  
CASE 846A



SOIC-8  
CASE 751



SOIC-14 NB  
CASE 751A



TSSOP-14  
CASE 948G

### DEVICE MARKING INFORMATION

See general marking information in the device marking section on page 2 of this data sheet.

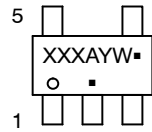
### ORDERING INFORMATION

See detailed ordering and shipping information on page 3 of this data sheet.

# TLV271, TLV272, NCV272, TLV274, NCV274

## MARKING DIAGRAMS

### Single Channel Configuration TLV271

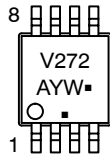


**TSOP-5  
CASE 483**

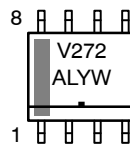
XXX = ADG (TLV271SN1T1G)  
 = ADH (TLV271SN2T1G)  
 A = Assembly Location  
 Y = Year  
 W = Work Week  
 ■ = Pb-Free Package

(Note: Microdot may be in either location)

### Dual Channel Configuration TLV272, NCV272

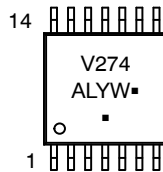


**Micro8  
CASE 846A**

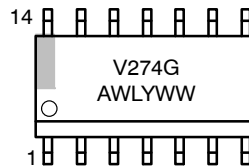


**SOIC-8  
CASE 751**

### Quad Channel Configuration TLV274, NCV274



**TSSOP-14  
CASE 948G**



**SOIC-14 NB  
CASE 751A**

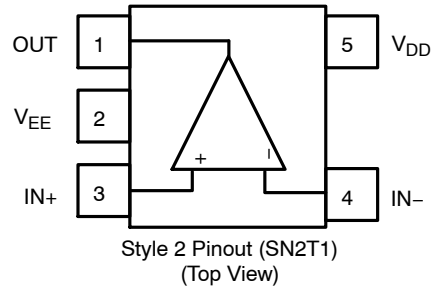
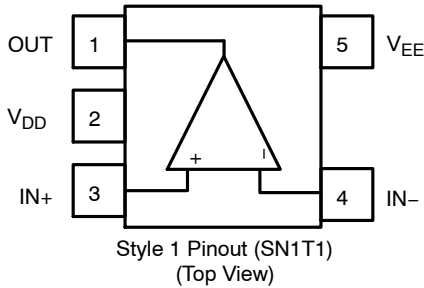
XXXXX = Specific Device Code  
 A = Assembly Location  
 WL, L = Wafer Lot  
 Y = Year  
 WW, W = Work Week  
 G or ■ = Pb-Free Package

(Note: Microdot may be in either location)

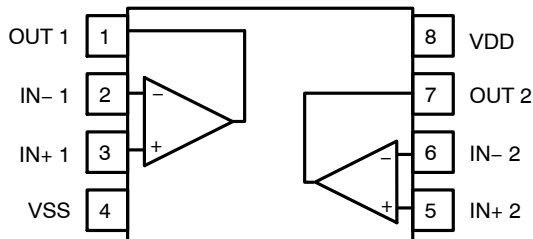
# TLV271, TLV272, NCV272, TLV274, NCV274

## PIN CONNECTIONS

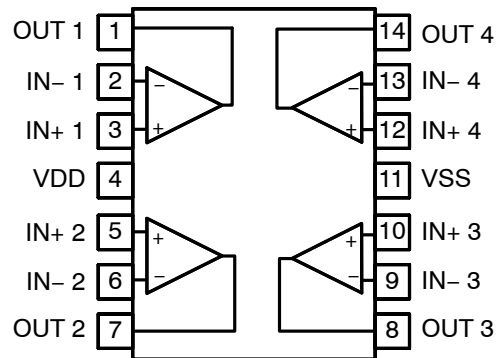
### Single Channel Configuration TLV271



### Dual Channel Configuration TLV272, NCV272



### Quadruple Channel Configuration TLV274, NCV274



## ORDERING INFORMATION

Device	Configuration	Automotive	Marking	Package	Shipping†	
TLV271SN1T1G (Style 1 Pinout)	Single	No	ADG	TSOP-5	3000 / Tape and Reel	
TLV271SN2T1G (Style 2 Pinout)			ADH		3000 / Tape and Reel	
TLV272DR2G (In Development)	Dual		V272	SOIC-8	2500 / Tape and Reel	
TLV272DMR2G			V272	Micro-8/MSOP-8	4000 / Tape and Reel	
TLV274DR2G (In Development)	Quad		V274	SOIC-14	2500 / Tape and Reel	
TLV274DTBR2G (In Development)			V274	TSSOP-14	2500 / Tape and Reel	
NCV272DR2G* (In Development)	Dual		Yes	V272	SOIC-8	2500 / Tape and Reel
NCV272DMR2G*				V272	Micro-8/MSOP-8	4000 / Tape and Reel
NCV274DR2G* (In Development)	Quad	V274		SOIC-14	2500 / Tape and Reel	
NCV274DTBR2G* (In Development)		V274		TSSOP-14	2500 / Tape and Reel	

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

# TLV271, TLV272, NCV272, TLV274, NCV274

## MAXIMUM RATINGS

Symbol	Rating	Value	Unit
V <sub>DD</sub>	Supply Voltage (Note 1)	TLV271 16.5	V
		TLV/NCV272/274 36	V
V <sub>ID</sub>	Input Differential Voltage	± Supply Voltage	V
V <sub>I</sub>	Input Common Mode Voltage Range (Note 1)	-0.2 V to (V <sub>DD</sub> + 0.2 V)	V
I <sub>I</sub>	Maximum Input Current	± 10	mA
I <sub>O</sub>	Output Current Range	± 100	mA
	Continuous Total Power Dissipation (Note 1)	200	mW
T <sub>J</sub>	Maximum Junction Temperature	150	°C
T <sub>A</sub>	Operating Ambient Temperature Range (free-air)	-40 to 125	°C
T <sub>STG</sub>	Storage Temperature Range	-65 to 150	°C
ESD <sub>HBM</sub>	ESD Capability, Human Body Model	2	kV
ESD <sub>CDM</sub>	ESD Capability, Charged Device Model	TLV271 TBD	kV
		TLV/NCV272 2	kV
		TLV/NCV274 1	kV
	Mounting Temperature (Infrared or Convection – 20 sec)	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Continuous short-circuit operation to ground at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of 150°C. Output currents in excess of 45 mA over long term may adversely affect reliability. Shorting output to either V+ or V- will adversely affect reliability.

## THERMAL INFORMATION

Parameter	Symbol	Package	Single Layer Board (Note 2)	Multi-Layer Board (Note 3)	Unit
Junction-to-Ambient	θ <sub>JA</sub>	TSOP-5	333	195	°C/W
		Micro-8 / MSOP-8	236	167	
		SOIC-8	190	131	
		SOIC-14	142	101	
		TSSOP-14	179	128	

2. Values based on a 1S standard PCB according to JEDEC51-3 with 1.0 oz copper and a 300 mm<sup>2</sup> copper area
3. Values based on a 1S2P standard PCB according to JEDEC51-7 with 1.0 oz copper and a 100 mm<sup>2</sup> copper area

# TLV271, TLV272, NCV272, TLV274, NCV274

## TLV271 DC ELECTRICAL CHARACTERISTICS

( $V_{DD} = 2.7V, 3.3V, 5V$  &  $\pm 5V$  (Note 4),  $T_A = 25^\circ C$ ,  $R_L \geq 10\text{ k}\Omega$  unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit	
Input Offset Voltage	$V_{IO}$	$V_{IC} = V_{DD}/2, V_O = V_{DD}/2, R_L = 10\text{ k}\Omega, R_S = 50\ \Omega$		0.5	5	mV	
		$T_A = -40^\circ C$ to $+105^\circ C$			7		
Offset Voltage Drift	$ICV_{OS}$	$V_{IC} = V_{DD}/2, V_O = V_{DD}/2, R_L = 10\text{ k}\Omega, R_S = 50\ \Omega$		2		$\mu V/^\circ C$	
Common Mode Rejection Ratio	CMRR	$0\text{ V} \leq V_{IC} \leq V_{DD} - 1.35\text{ V}, R_S = 50\ \Omega$	$V_{DD} = 2.7\text{ V}$	58	70	dB	
		$T_A = -40^\circ C$ to $+105^\circ C$		55			
		$0\text{ V} \leq V_{IC} \leq V_{DD} - 1.35\text{ V}, R_S = 50\ \Omega$	$V_{DD} = 5\text{ V}$	65	130		
		$T_A = -40^\circ C$ to $+105^\circ C$		62			
		$0\text{ V} \leq V_{IC} \leq V_{DD} - 1.35\text{ V}, R_S = 50\ \Omega$	$V_{DD} = \pm 5\text{ V}$	69	140		
$T_A = -40^\circ C$ to $+105^\circ C$	66						
Power Supply Rejection Ratio	PSRR	$V_{DD} = 2.7\text{ V}$ to $16\text{ V}, V_{IC} = V_{DD}/2, \text{ No Load}$		70	135	dB	
		$T_A = -40^\circ C$ to $+105^\circ C$		65			
Large Signal Voltage Gain	$A_{VD}$	$V_{O(pp)} = V_{DD}/2, R_L = 10\text{ k}\Omega$	$V_{DD} = 2.7\text{ V}$	97	106	dB	
		$T_A = -40^\circ C$ to $+105^\circ C$		76			
		$V_{O(pp)} = V_{DD}/2, R_L = 10\text{ k}\Omega$	$V_{DD} = 3.3\text{ V}$	97	123		
		$T_A = -40^\circ C$ to $+105^\circ C$		76			
		$V_{O(pp)} = V_{DD}/2, R_L = 10\text{ k}\Omega$	$V_{DD} = 5\text{ V}$	100	127		
		$T_A = -40^\circ C$ to $+105^\circ C$		86			
		$V_{O(pp)} = V_{DD}/2, R_L = 10\text{ k}\Omega$	$V_{DD} = \pm 5\text{ V}$	100	130		
$T_A = -40^\circ C$ to $+105^\circ C$	90						
Input Bias Current	$I_B$	$V_{DD} = 5\text{ V}, V_{IC} = V_{DD}/2, V_O = V_{DD}/2, R_S = 50\ \Omega$	$T_A = 25^\circ C$		45	150	pA
			$T_A = 105^\circ C$			1000	
Input Offset Current	$I_{IO}$	$V_{DD} = 5\text{ V}, V_{IC} = V_{DD}/2, V_O = V_{DD}/2, R_S = 50\ \Omega$	$T_A = 25^\circ C$		45	150	pA
			$T_A = 105^\circ C$			1000	
Differential Input Resistance	$r_{i(d)}$			1000		G $\Omega$	
Common-mode Input Capacitance	$C_{IC}$	$f = 21\text{ kHz}$		8		pF	

4.  $V_{DD} = \pm 5\text{ V}$  is shorthand for  $V_{DD} = +5\text{ V}$  and  $V_{EE} = -5\text{ V}$ .

# TLV271, TLV272, NCV272, TLV274, NCV274

## TLV271 DC ELECTRICAL CHARACTERISTICS

( $V_{DD} = 2.7V, 3.3V, 5V$  &  $\pm 5V$  (Note 4),  $T_A = 25^\circ C$ ,  $R_L \geq 10\text{ k}\Omega$  unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit		
Output Swing (High-level)	$V_{OH}$	$V_{IC} = V_{DD}/2, I_{OH} = -1\text{ mA}$	$V_{DD} = 2.7\text{ V}$	2.55	2.58	V		
		$T_A = -40^\circ C$ to $+105^\circ C$		2.48				
		$V_{IC} = V_{DD}/2, I_{OH} = -1\text{ mA}$	$V_{DD} = 3.3\text{ V}$	3.15	3.21			
		$T_A = -40^\circ C$ to $+105^\circ C$		3.00				
		$V_{IC} = V_{DD}/2, I_{OH} = -1\text{ mA}$	$V_{DD} = 5\text{ V}$	4.8	4.93			
		$T_A = -40^\circ C$ to $+105^\circ C$		4.75				
		$V_{IC} = V_{DD}/2, I_{OH} = -1\text{ mA}$	$V_{DD} = \pm 5\text{ V}$	4.92	4.96			
		$T_A = -40^\circ C$ to $+105^\circ C$		4.9				
		$V_{IC} = V_{DD}/2, I_{OH} = -5\text{ mA}$	$V_{DD} = 2.7\text{ V}$	1.9	2.1		V	
		$T_A = -40^\circ C$ to $+105^\circ C$		1.5				
		$V_{IC} = V_{DD}/2, I_{OH} = -5\text{ mA}$	$V_{DD} = 3.3\text{ V}$	2.5	2.89			
		$T_A = -40^\circ C$ to $+105^\circ C$		2.1				
		$V_{IC} = V_{DD}/2, I_{OH} = -5\text{ mA}$	$V_{DD} = 5\text{ V}$	4.5	4.68			
		$T_A = -40^\circ C$ to $+105^\circ C$		4.35				
		$V_{IC} = V_{DD}/2, I_{OH} = -5\text{ mA}$	$V_{DD} = \pm 5\text{ V}$	4.7	4.78			
		$T_A = -40^\circ C$ to $+105^\circ C$		4.65				
Output Swing (Low-level)	$V_{OL}$	$V_{IC} = V_{DD}/2, I_{OL} = -1\text{ mA}$	$V_{DD} = 2.7\text{ V}$		0.1	0.15		V
		$T_A = -40^\circ C$ to $+105^\circ C$				0.22		
		$V_{IC} = V_{DD}/2, I_{OL} = -1\text{ mA}$	$V_{DD} = 3.3\text{ V}$		0.03	0.15		
		$T_A = -40^\circ C$ to $+105^\circ C$				0.22		
		$V_{IC} = V_{DD}/2, I_{OL} = -1\text{ mA}$	$V_{DD} = 5\text{ V}$		0.03	0.1		
		$T_A = -40^\circ C$ to $+105^\circ C$				0.15		
		$V_{IC} = V_{DD}/2, I_{OL} = -1\text{ mA}$	$V_{DD} = \pm 5\text{ V}$		0.05	0.08		
		$T_A = -40^\circ C$ to $+105^\circ C$				0.1		
		$V_{IC} = V_{DD}/2, I_{OL} = -5\text{ mA}$	$V_{DD} = 2.7\text{ V}$		0.5	0.7	V	
		$T_A = -40^\circ C$ to $+105^\circ C$				1.1		
		$V_{IC} = V_{DD}/2, I_{OL} = -5\text{ mA}$	$V_{DD} = 3.3\text{ V}$		0.13	0.7		
		$T_A = -40^\circ C$ to $+105^\circ C$				1.1		
		$V_{IC} = V_{DD}/2, I_{OL} = -5\text{ mA}$	$V_{DD} = 5\text{ V}$		0.13	0.4		
		$T_A = -40^\circ C$ to $+105^\circ C$				0.5		
		$V_{IC} = V_{DD}/2, I_{OL} = -5\text{ mA}$	$V_{DD} = \pm 5\text{ V}$		0.16	0.3		
		$T_A = -40^\circ C$ to $+105^\circ C$				0.35		
Output Current	$I_O$	$V_O = 0.5\text{ V from rail}, V_{DD} = 2.7\text{ V}$	Positive rail	4.0		mA		
			Negative rail		5.0			
		$V_O = 0.5\text{ V from rail}, V_{DD} = 5\text{ V}$	Positive rail	7.0				
			Negative rail		8.0			
		$V_O = 0.5\text{ V from rail}, V_{DD} = 10\text{ V}$	Positive rail	13				
			Negative rail		12			

4.  $V_{DD} = \pm 5\text{ V}$  is shorthand for  $V_{DD} = +5\text{ V}$  and  $V_{EE} = -5\text{ V}$ .

# TLV271, TLV272, NCV272, TLV274, NCV274

## TLV271 DC ELECTRICAL CHARACTERISTICS

( $V_{DD} = 2.7V, 3.3V, 5V$  &  $\pm 5V$  (Note 4),  $T_A = 25^\circ C$ ,  $R_L \geq 10 k\Omega$  unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit	
Power Supply Quiescent Current	$I_{DD}$	$V_O = V_{DD}/2$	$V_{DD} = 2.7 V$		380	560	$\mu A$
			$V_{DD} = 3.3 V$		385	620	
			$V_{DD} = 5 V$		390	660	
			$V_{DD} = 10 V$		400	800	
		$T_A = -40^\circ C$ to $+105^\circ C$			1000		

4.  $V_{DD} = \pm 5 V$  is shorthand for  $V_{DD} = +5 V$  and  $V_{EE} = -5 V$ .

## TLV271 AC ELECTRICAL CHARACTERISTICS

( $V_{DD} = 2.7 V, 5 V$ , &  $\pm 5 V$  (Note 5),  $T_A = 25^\circ C$ , and  $R_L \geq 10 k\Omega$  unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit	
Unity Gain Bandwidth	UGBW	$R_L = 2 k\Omega, C_L = 10 pF$	$V_{DD} = 2.7 V$		3.2	MHz	
			$V_{DD} = 5 V$ to $10 V$		3.5		
Slew Rate at Unity Gain	SR	$V_{O(pp)} = V_{DD}/2, R_L = 10 k\Omega, C_L = 50 pF$	$V_{DD} = 2.7 V$		1.35	$V/\mu S$	
				$T_A = -40^\circ C$ to $+105^\circ C$			1
		$V_{O(pp)} = V_{DD}/2, R_L = 10 k\Omega, C_L = 50 pF$	$V_{DD} = 5 V$		1.45		2.3
				$T_A = -40^\circ C$ to $+105^\circ C$			1.2
		$V_{O(pp)} = V_{DD}/2, R_L = 10 k\Omega, C_L = 50 pF$	$V_{DD} = \pm 5 V$		1.8		2.6
$T_A = -40^\circ C$ to $+105^\circ C$				1.3			
Phase Margin	$\theta_m$	$R_L = 2 k\Omega, C_L = 10 pF$		45		$^\circ$	
Gain Margin		$R_L = 2 k\Omega, C_L = 10 pF$		14		dB	
Settling Time to 0.1%	$t_S$	$V$ -step(pp) = 1 V, AV = -1, $R_L = 2 k\Omega, C_L = 10 pF$	$V_{DD} = 2.7 V$		2.9	$\mu S$	
			$V_{DD} = 5 V, \pm 5 V$		2.0		
Total Harmonic Distortion plus Noise	THD+N	$V_{DD} = 2.7 V, V_{O(pp)} = V_{DD}/2, R_L = 2 k\Omega, f = 10 kHz$	AV = 1		0.004	%	
			AV = 10		0.04		
			AV = 100		0.3		
		$V_{DD} = 5 V, \pm 5 V, V_{O(pp)} = V_{DD}/2, R_L = 2 k\Omega, f = 10 kHz$	AV = 1		0.004		
			AV = 10		0.04		
Input-Referred Voltage Noise	$e_n$	f = 1 kHz		30	$nV/\sqrt{Hz}$		
		f = 10 kHz		20			
Input-Referred Current Noise	$i_n$	f = 1 kHz		0.6	$fA/\sqrt{Hz}$		

5.  $V_{DD} = \pm 5 V$  is shorthand for  $V_{DD} = +5 V$  and  $V_{EE} = -5 V$ .

# TLV271, TLV272, NCV272, TLV274, NCV274

## TLV/NCV 272/274 DC ELECTRICAL CHARACTERISTICS

( $V_{DD} = 2.7\text{ V}, 5\text{ V}, 10\text{ V}, 36\text{ V}$ ),  $T_A = 25^\circ\text{C}$ ,  $R_L \geq 10\text{ k}\Omega$  unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit	
Input Offset Voltage	$V_{IO}$	$V_{IC} = V_{DD}/2$ , $V_O = V_{DD}/2$ , $R_L = 10\text{ k}\Omega$		1.3	$\pm 3$	mV	
		$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$			$\pm 4$		
Offset Voltage Drift	$ICV_{OS}$	$V_{IC} = V_{DD}/2$ , $V_O = V_{DD}/2$ , $R_L = 10\text{ k}\Omega$		2		$\mu\text{V}/^\circ\text{C}$	
Common Mode Rejection Ratio	CMRR	$V_{CM} = V_{SS} + 0.2\text{ V}$ to $V_{DD} - 1.35\text{ V}$	$V_{DD} = 2.7\text{ V}$	90	110	dB	
		$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$		69			
		$V_{CM} = V_{SS} + 0.2\text{ V}$ to $V_{DD} - 1.35\text{ V}$	$V_{DD} = 5\text{ V}$	102	125		
		$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$		80			
		$V_{CM} = V_{SS} + 0.2\text{ V}$ to $V_{DD} - 1.35\text{ V}$	$V_{DD} = 10\text{ V}$	110	130		
		$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$		87			
		$V_{CM} = V_{SS} + 0.2\text{ V}$ to $V_{DD} - 1.35\text{ V}$	$V_{DD} = 36\text{ V}$	120	145		
$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$ (TLV/NCV272) (TLV/NCV274)	95 85						
Power Supply Rejection Ratio	PSRR	$V_{DD} = 2.7\text{ V}$ to $36\text{ V}$ , $V_{IC} = V_{DD}/2$ , No Load	114	135		dB	
		$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$	100				
Large Signal Voltage Gain	$A_{VD}$	$V_{O(pp)} = V_{DD}/2$ , $R_L = 10\text{ k}\Omega$	$V_{DD} = 2.7\text{ V}$	96	118	dB	
		$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$		86			
		$V_{O(pp)} = V_{DD}/2$ , $R_L = 10\text{ k}\Omega$	$V_{DD} = 5\text{ V}$	96	120		
		$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$		86			
		$V_{O(pp)} = V_{DD}/2$ , $R_L = 10\text{ k}\Omega$	$V_{DD} = 10\text{ V}$	98	120		
		$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$		88			
		$V_{O(pp)} = V_{DD}/2$ , $R_L = 10\text{ k}\Omega$	$V_{DD} = 36\text{ V}$	98	120		
$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$	88						
Input Bias Current	$I_B$	$V_{DD} = 5\text{ V}$ , $V_{IC} = V_{DD}/2$ , $V_O = V_{DD}/2$	$T_A = 25^\circ\text{C}$	5	200	pA	
		$V_{DD} = 2.7$ to $36\text{ V}$ , $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$	TLV/NCV272		<b>2000</b>		
			TLV/NCV274		<b>1500</b>		
Input Offset Current	$I_{IO}$	$V_{DD} = 5\text{ V}$ , $V_{IC} = V_{DD}/2$ , $V_O = V_{DD}/2$ , $R_S = 50\ \Omega$	$T_A = 25^\circ\text{C}$	2	75	pA	
			TLV/NCV272		<b>500</b>		
		$V_{DD} = 2.7$ to $36\text{ V}$ , $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$	TLV/NCV274		<b>200</b>		
Channel Separation	XTLK	DC	TLV/NCV272	100		dB	
			TLV/NCV274	115		dB	
Differential Input Resistance	$R_{i(d)}$			5		G $\Omega$	
Common-mode Input Capacitance	$C_{IC}$			3.5		pF	



# TLV271, TLV272, NCV272, TLV274, NCV274

## TLV/NCV 272/274 DC ELECTRICAL CHARACTERISTICS

( $V_{DD} = 2.7\text{ V}, 5\text{ V}, 10\text{ V}, 36\text{ V}$ ),  $T_A = 25^\circ\text{C}$ ,  $R_L \geq 10\text{ k}\Omega$  unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit	
Output Swing (High-level)	$V_{OH}$	$V_{IC} = V_{DD}/2$	$V_{DD} = 2.7\text{ V}$		0.006	0.15	V
		$T_A = -40^\circ\text{C to } +125^\circ\text{C}$				<b>0.22</b>	
		$V_{IC} = V_{DD}/2$	$V_{DD} = 5\text{ V}$		0.013	0.20	
		$T_A = -40^\circ\text{C to } +125^\circ\text{C}$				<b>0.25</b>	
		$V_{IC} = V_{DD}/2$	$V_{DD} = 10\text{ V}$		0.023	0.08	
		$T_A = -40^\circ\text{C to } +125^\circ\text{C}$				<b>0.10</b>	
		$V_{IC} = V_{DD}/2$	$V_{DD} = 36\text{ V}$		0.074	0.10	
$T_A = -40^\circ\text{C to } +125^\circ\text{C}$		<b>0.15</b>					
Output Swing (Low-level)	$V_{OL}$	$V_{IC} = V_{DD}/2$	$V_{DD} = 2.7\text{ V}$		0.005	0.15	V
		$T_A = -40^\circ\text{C to } +125^\circ\text{C}$				<b>0.22</b>	
		$V_{IC} = V_{DD}/2$	$V_{DD} = 5\text{ V}$		0.01	0.10	
		$T_A = -40^\circ\text{C to } +125^\circ\text{C}$				<b>0.15</b>	
		$V_{IC} = V_{DD}/2$	$V_{DD} = 10\text{ V}$		0.022	0.3	
		$T_A = -40^\circ\text{C to } +125^\circ\text{C}$				<b>0.35</b>	
		$V_{IC} = V_{DD}/2$	$V_{DD} = 36\text{ V}$		0.065	0.3	
$T_A = -40^\circ\text{C to } +125^\circ\text{C}$		<b>0.35</b>					
Output Current	$I_O$	$V_{DD} = 2.7\text{ V}$	Positive rail		50		mA
			Negative rail		70		
		$V_{DD} = 5\text{ V}$	Positive rail		60		
			Negative rail		50		
		$V_{DD} = 10\text{ V}$	Positive rail		65		
			Negative rail		50		
		$V_{DD} = 36\text{ V}$	Positive rail		65		
Negative rail			50				
Power Supply Quiescent Current	$I_{DD}$	$V_O = V_{DD}/2$ , Per channel, no load	$V_{DD} = 2.7\text{ V}$		405	525	$\mu\text{A}$
			$V_{DD} = 5\text{ V}$		410	530	
			$V_{DD} = 10\text{ V}$		416	540	
			$V_{DD} = 36\text{ V}$		465	600	
		$T_A = -40^\circ\text{C to } +105^\circ\text{C}$			<b>700</b>		

NOTE: Power dissipation must be limited to prevent junction temperature from exceeding  $150^\circ\text{C}$ . See Absolute Maximum Ratings for more information.

# TLV271, TLV272, NCV272, TLV274, NCV274

## TLV/NCV 272/274 AC ELECTRICAL CHARACTERISTICS

(( $V_{DD} = 2.7\text{ V}, 5\text{ V}, 10\text{ V}, 36\text{ V}$ ),  $T_A = 25^\circ\text{C}$ , and  $R_L \geq 10\text{ k}\Omega$  unless otherwise noted)

Parameter	Symbol	Conditions		Min	Typ	Max	Unit
Unity Gain Bandwidth	UGBW	$C_L = 25\text{ pF}$	$V_{DD} = 2.7\text{ V}$		3		MHz
Slew Rate at Unity Gain	SR	$C_L = 20\text{ pF}, R_L = 2\text{ k}\Omega$	$V_{DD} = 2.7\text{ V}$		2.8		V/ $\mu\text{S}$
			$V_{DD} = 5\text{ V}$		2.7		
			$V_{DD} = 10\text{ V}$		2.6		
			$V_{DD} = 36\text{ V}$		2.4		
Phase Margin	$\theta_m$	$C_L = 25\text{ pF}$			50		$^\circ$
Gain Margin		$C_L = 25\text{ pF}$			14		dB
Settling Time to 0.1%	$t_S$	$V_O = 1\text{ V}_{pp}, \text{Gain} = 1, C_L = 20\text{ pF}$	$V_{DD} = 2.7\text{ V}$		0.6		$\mu\text{S}$
		$V_O = 3\text{ V}_{pp}, \text{Gain} = 1, C_L = 20\text{ pF}$	$V_{DD} = 5\text{ V}$		1.2		
		$V_O = 8.5\text{ V}_{pp}, \text{Gain} = 1, C_L = 20\text{ pF}$	$V_{DD} = 10\text{ V}$		3.4		
		$V_O = 10\text{ V}_{pp}, \text{Gain} = 1, C_L = 20\text{ pF}$	$V_{DD} = 36\text{ V}$		3.2		
Total Harmonic Distortion plus Noise	THD+N	$V_{IN} = 0.5\text{ V}_{pp}, f = 1\text{ kHz}, A_v = 1$	$V_{DD} = 2.7\text{ V}$		0.05		%
		$V_{IN} = 2.5\text{ V}_{pp}, f = 1\text{ kHz}, A_v = 1$	$V_{DD} = 5\text{ V}$		0.009		
		$V_{IN} = 7.5\text{ V}_{pp}, f = 1\text{ kHz}, A_v = 1$	$V_{DD} = 10\text{ V}$		0.004		
		$V_{IN} = 28.5\text{ V}_{pp}, f = 1\text{ kHz}, A_v = 1$	$V_{DD} = 36\text{ V}$		0.001		
Input-Referred Voltage Noise	$e_n$	$f = 1\text{ kHz}$			30		nV/ $\sqrt{\text{Hz}}$
		$f = 10\text{ kHz}$			20		
Input-Referred Current Noise	$i_n$	$f = 1\text{ kHz}$			90		fA/ $\sqrt{\text{Hz}}$

# TLV271, TLV272, NCV272, TLV274, NCV274

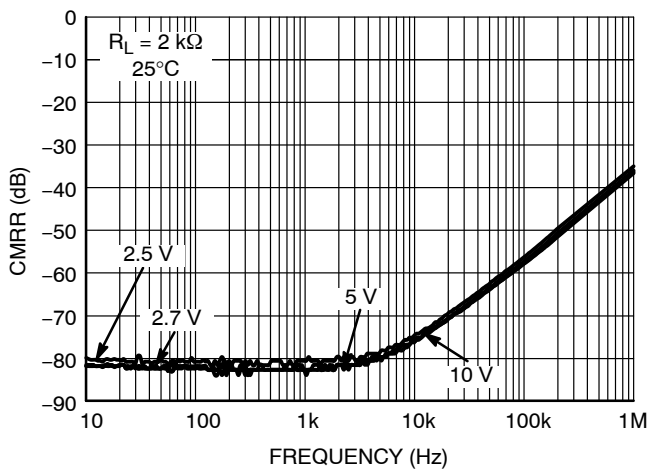


Figure 1. CMRR vs. Frequency for TLV271

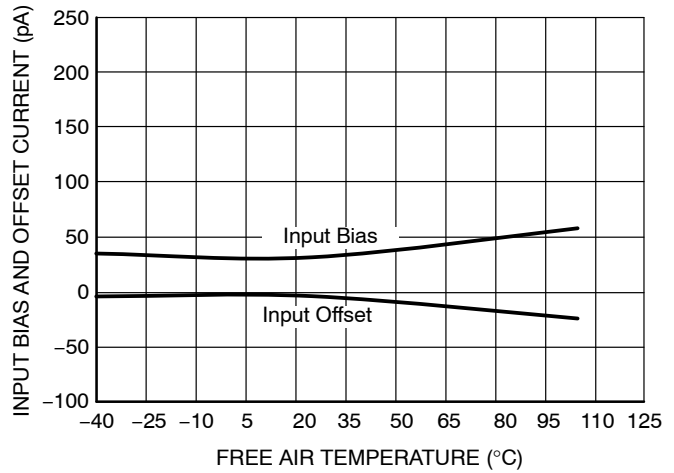


Figure 2. Input Bias and Offset Current vs. Temperature for TLV271

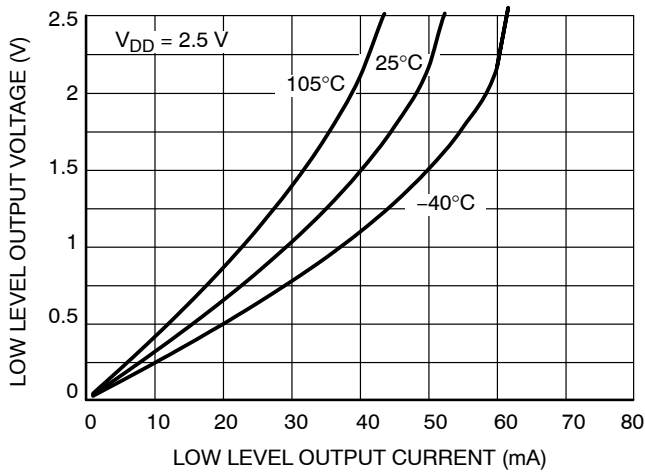


Figure 3. 2.5 V  $V_{OL}$  vs.  $I_{out}$

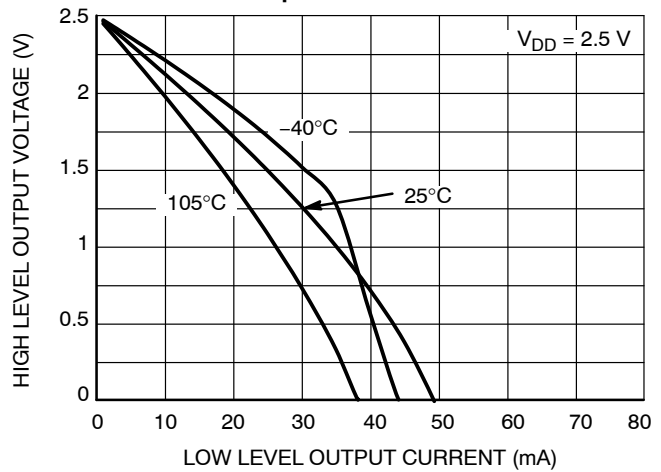


Figure 4. 2.5 V  $V_{OH}$  vs.  $I_{out}$

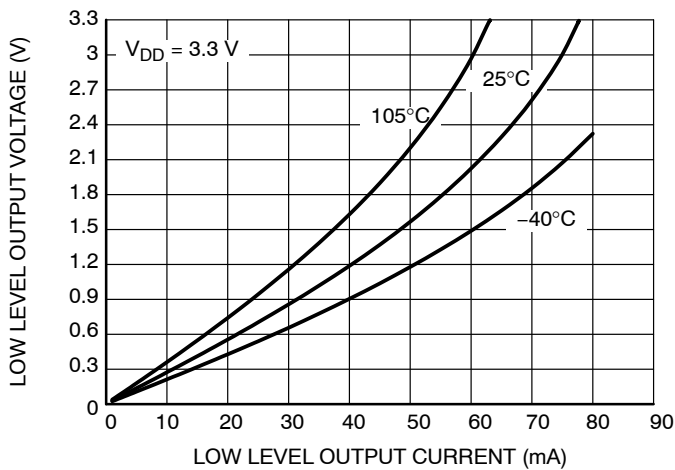


Figure 5. 3.3 V  $V_{OL}$  vs.  $I_{out}$

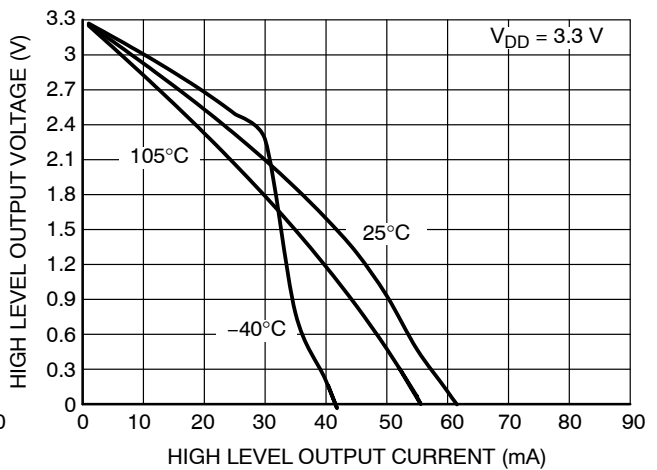


Figure 6. 3.3 V  $V_{OH}$  vs.  $I_{out}$

TLV271, TLV272, NCV272, TLV274, NCV274

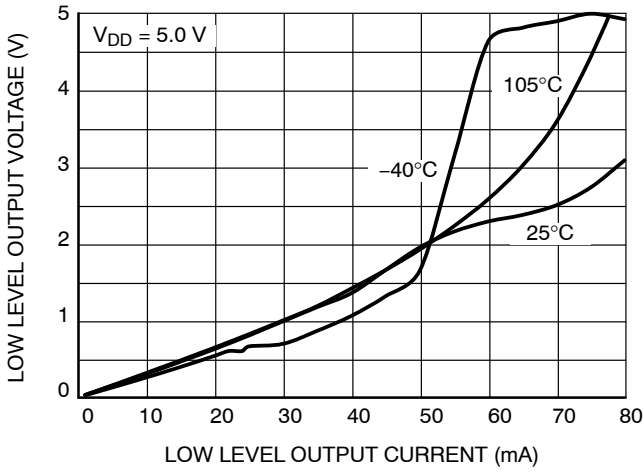


Figure 7.  $V_{OL}$  vs.  $I_{out}$

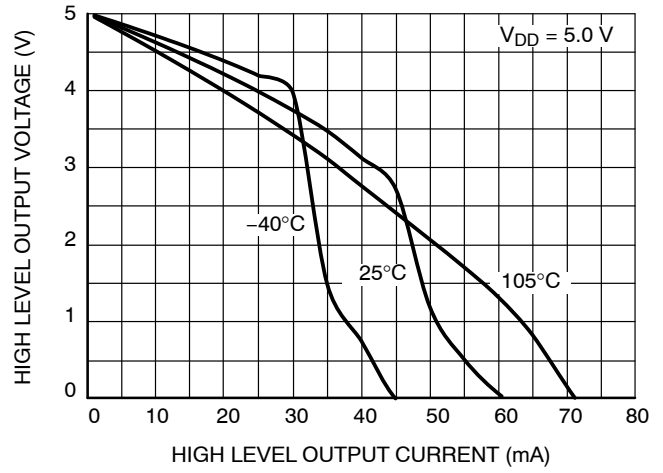


Figure 8.  $V_{OH}$  vs.  $I_{out}$

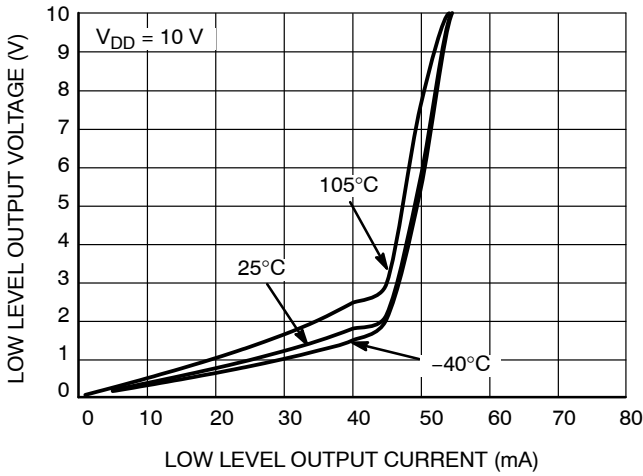


Figure 9. 10 V  $V_{OL}$  vs.  $I_{out}$

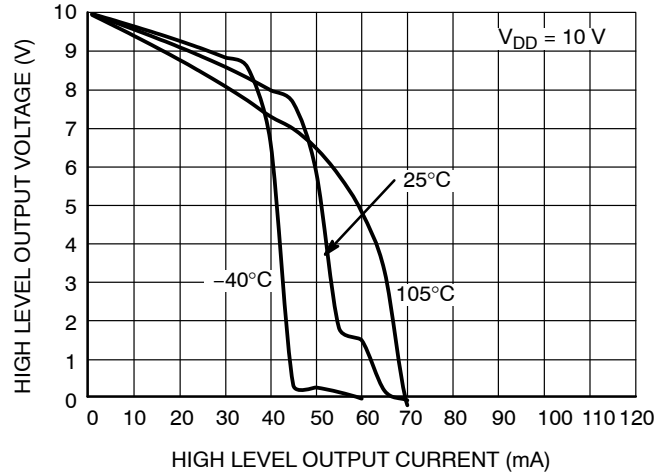


Figure 10. 10 V  $V_{OH}$  vs.  $I_{out}$

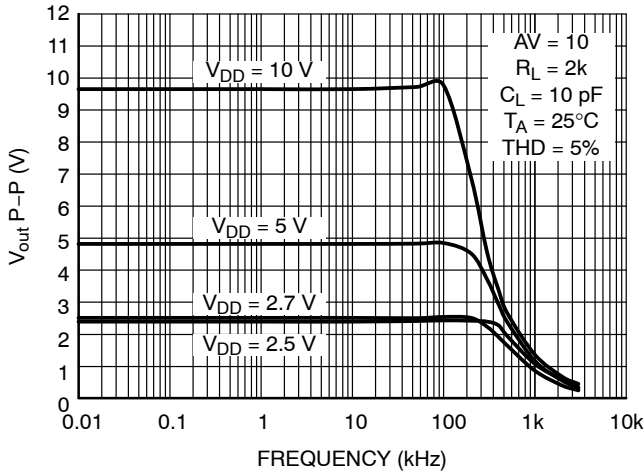


Figure 11. Peak-to-Peak Output vs. Supply vs. Frequency

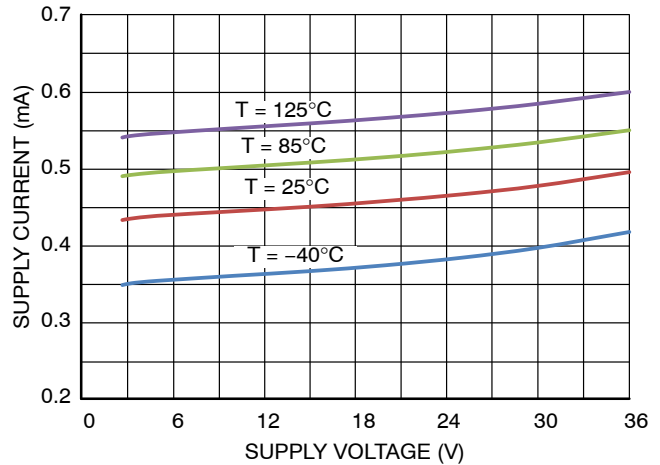


Figure 12. Quiescent Current Per Channel vs. Supply Voltage for TLV/NCV272/274

TLV271, TLV272, NCV272, TLV274, NCV274

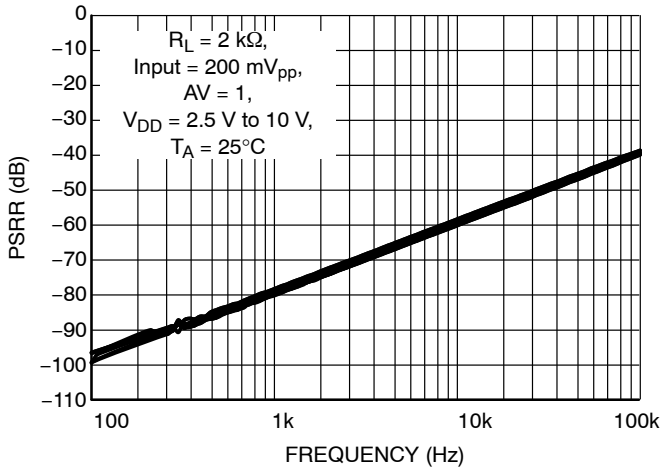


Figure 13. PSRR vs. Frequency for TLV271

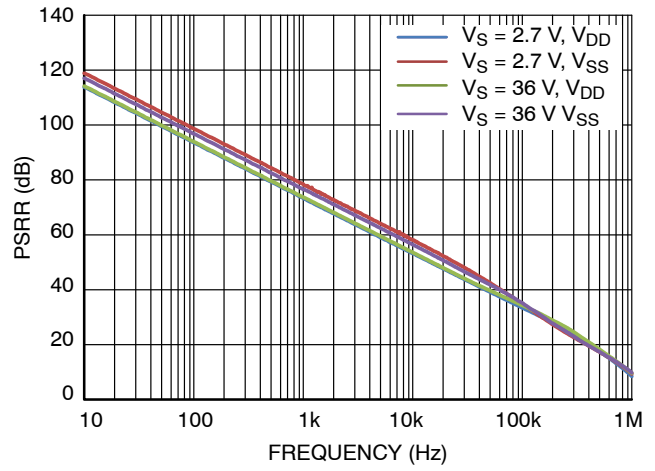


Figure 14. PSRR vs. Frequency for TLV/NCV272/274

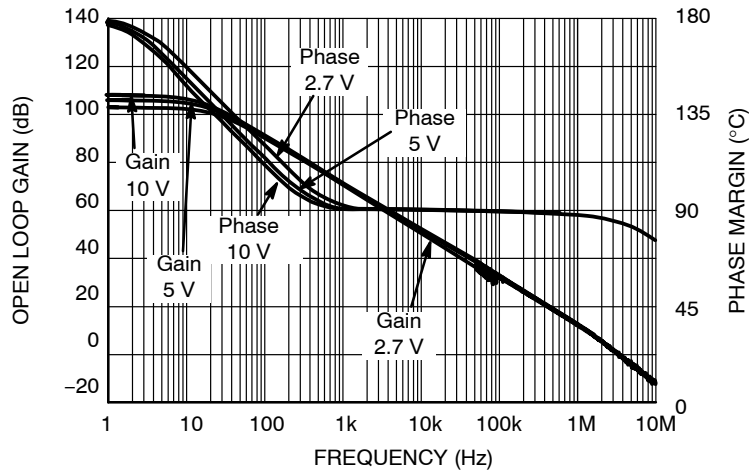


Figure 15. Open Loop Gain and Phase vs. Frequency

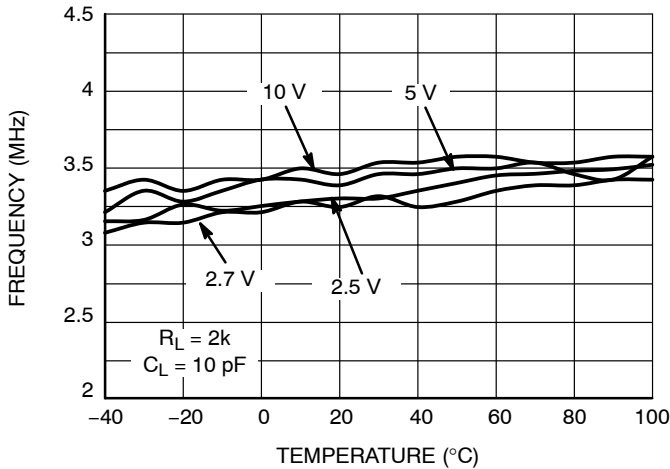


Figure 16. Gain Bandwidth Product vs. Temperature

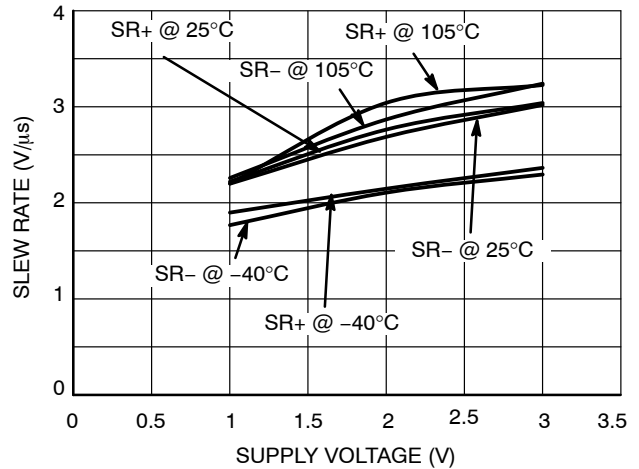


Figure 17. Slew Rate vs. Supply Voltage

# TLV271, TLV272, NCV272, TLV274, NCV274

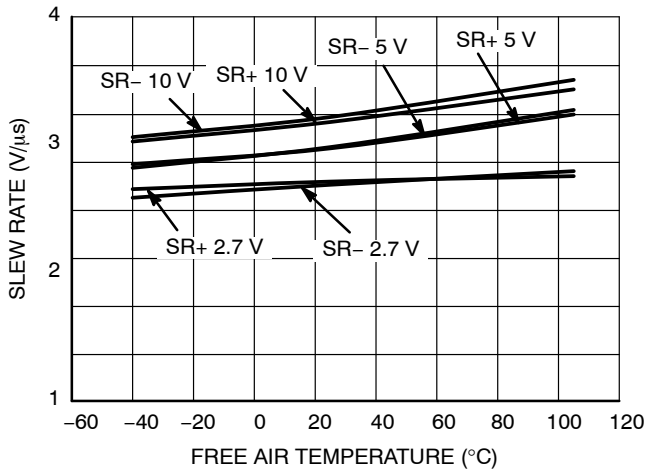


Figure 18. Slew Rate vs. Temperature

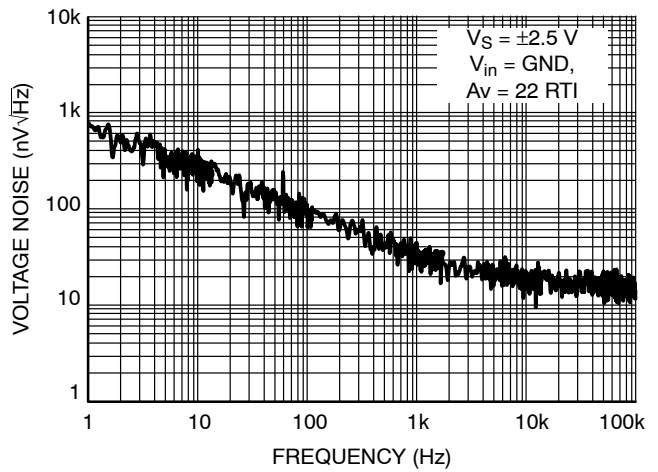


Figure 19. Voltage Noise vs. Frequency

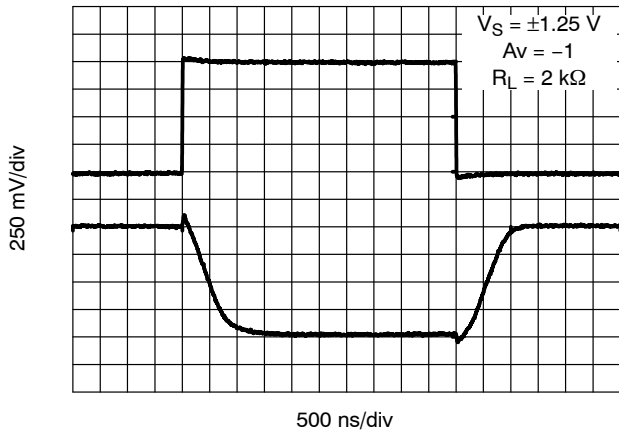


Figure 20. 2.5 V Inverting Large Signal Pulse Response

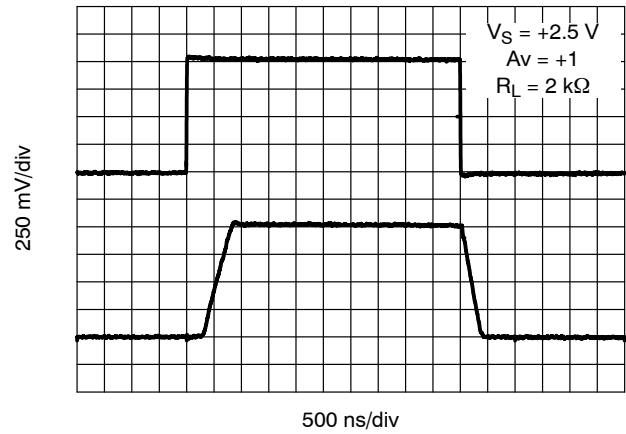


Figure 21. 2.5 V Non-Inverting Large Signal Pulse Response

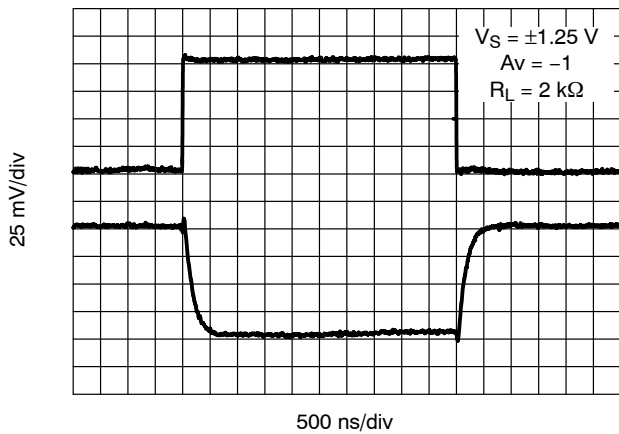


Figure 22. 2.5 V Inverting Small Signal Pulse Response

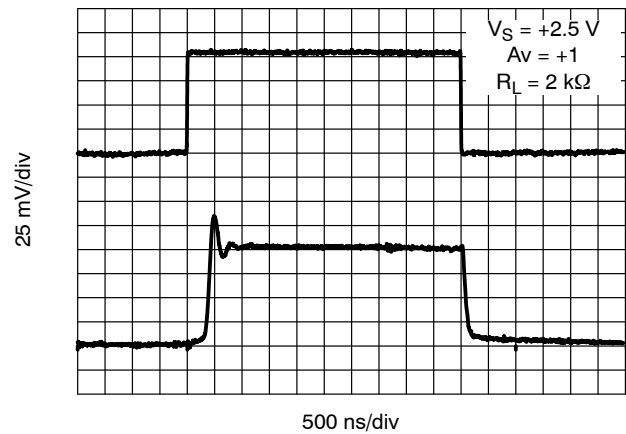
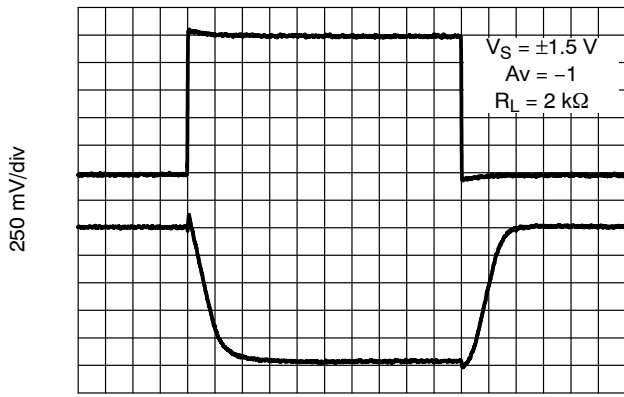
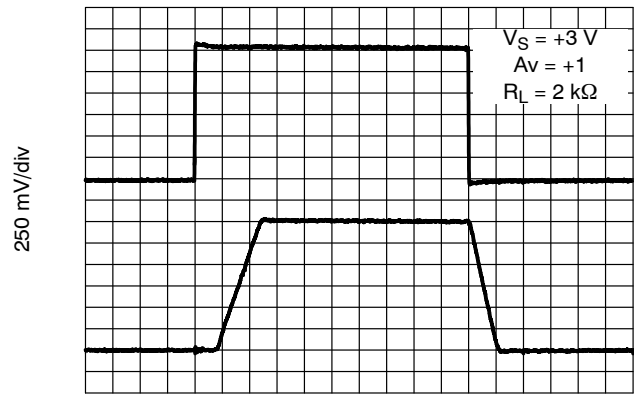


Figure 23. 2.5 V Non-Inverting Small Signal Pulse Response



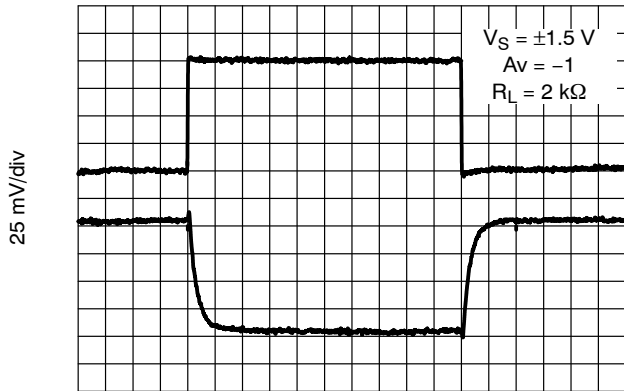
500 ns/div

Figure 24. 3 V Inverting Large Signal Pulse Response



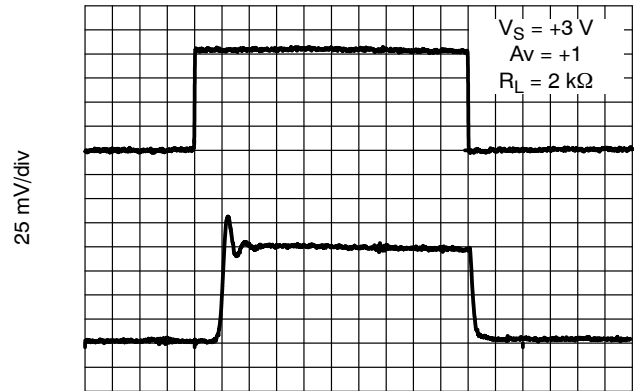
500 ns/div

Figure 25. 3 V Non-Inverting Large Signal Pulse Response



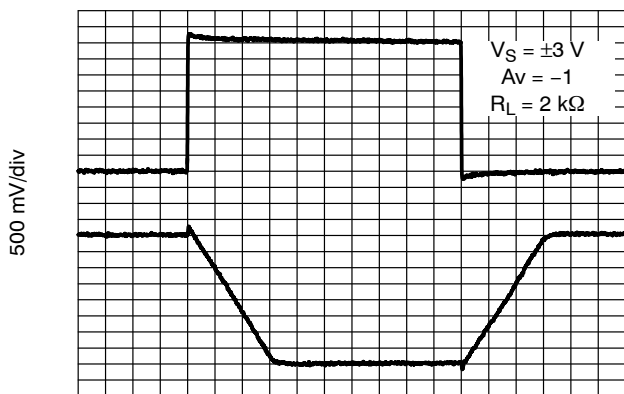
500 ns/div

Figure 26. 3 V Inverting Small Signal Pulse Response



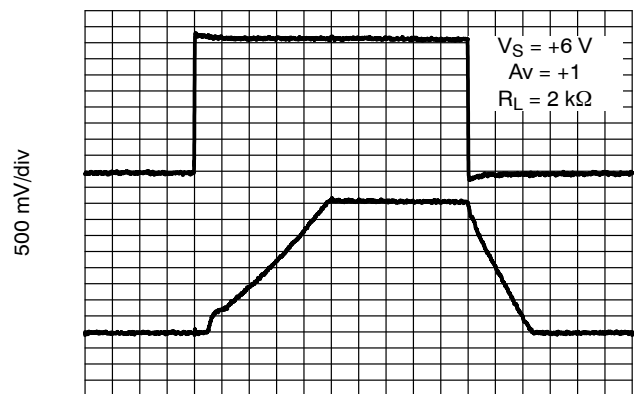
500 ns/div

Figure 27. 3 V Non-Inverting Small Signal Pulse Response



500 ns/div

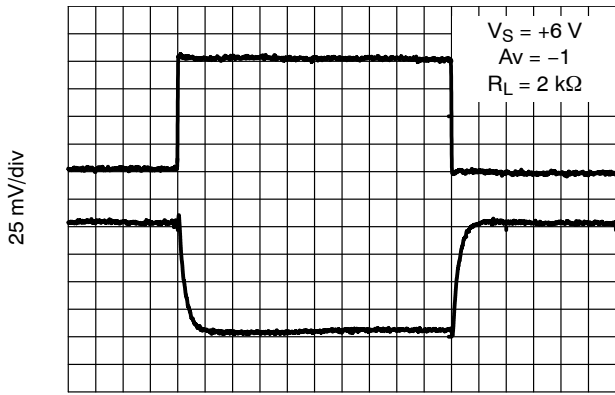
Figure 28. 6 V Inverting Large Signal Pulse Response



500 ns/div

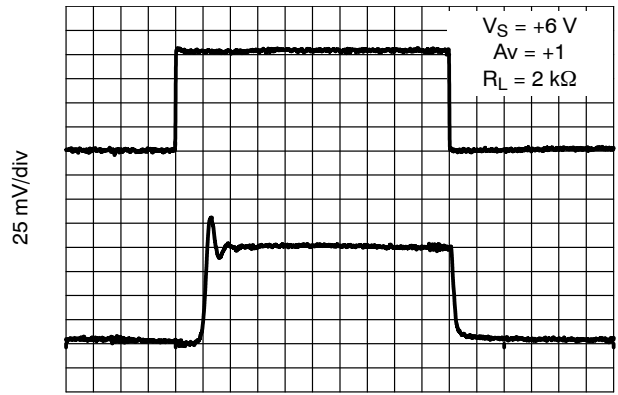
Figure 29. 6 V Non-Inverting Large Signal Pulse Response

TLV271, TLV272, NCV272, TLV274, NCV274



500 ns/div

Figure 30. 6 V Inverting Small Signal Pulse Response



500 ns/div

Figure 31. 6 V Non-Inverting Small Signal Pulse Response

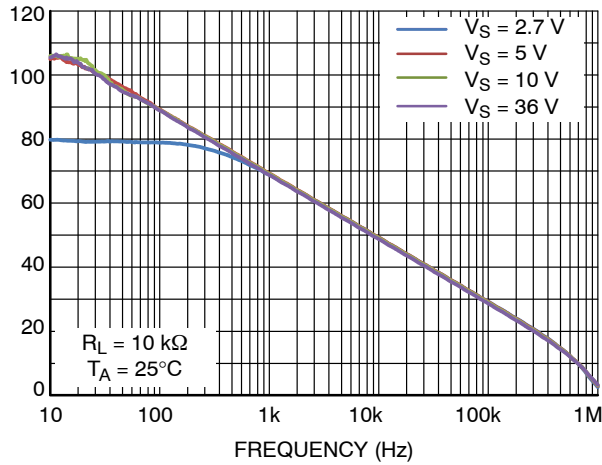


Figure 32. CMRR vs. Frequency for TLV/NCV272/274

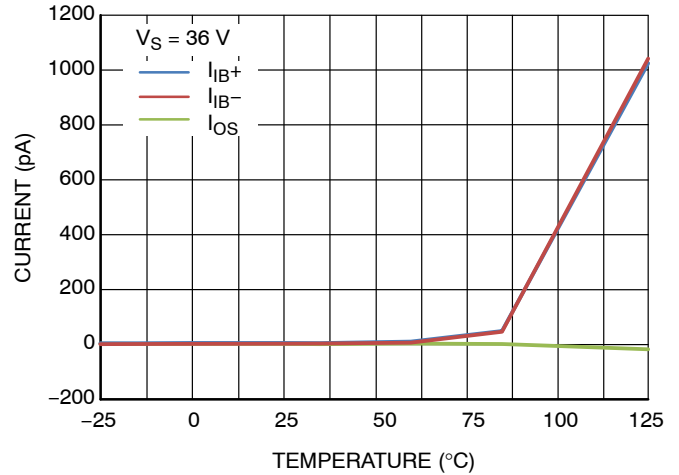


Figure 33. Input Bias and Offset Current vs. Temperature for TLV/NCV272/274

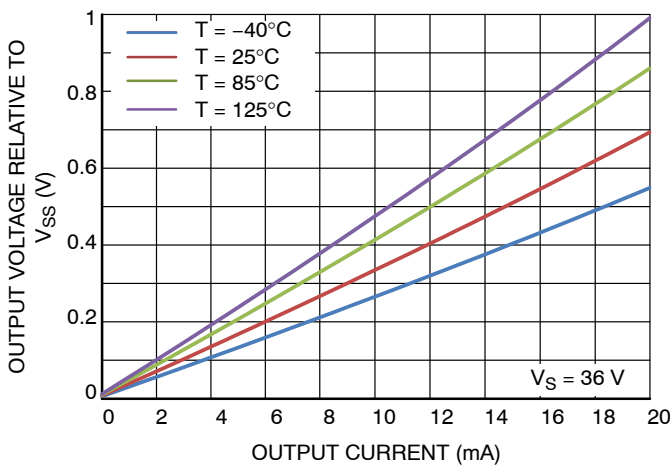


Figure 34. Low Level Output vs. Output Current for TLV/NCV272/274

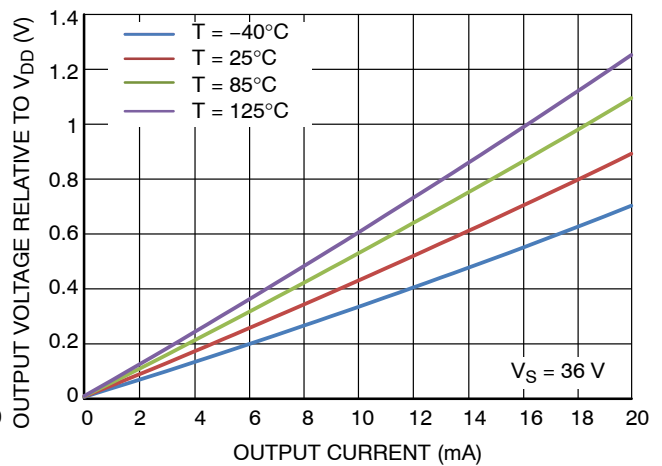
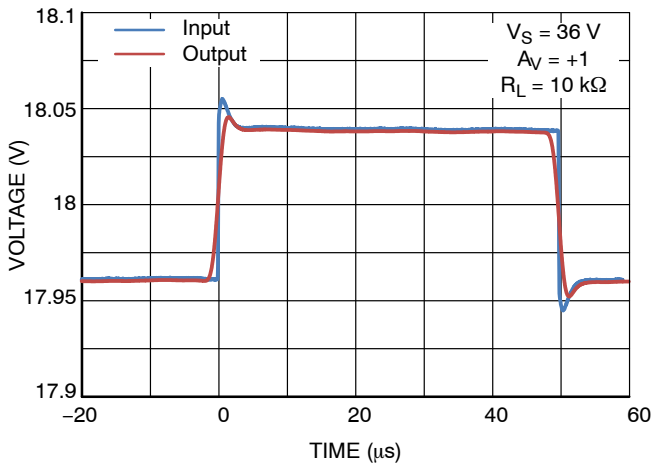


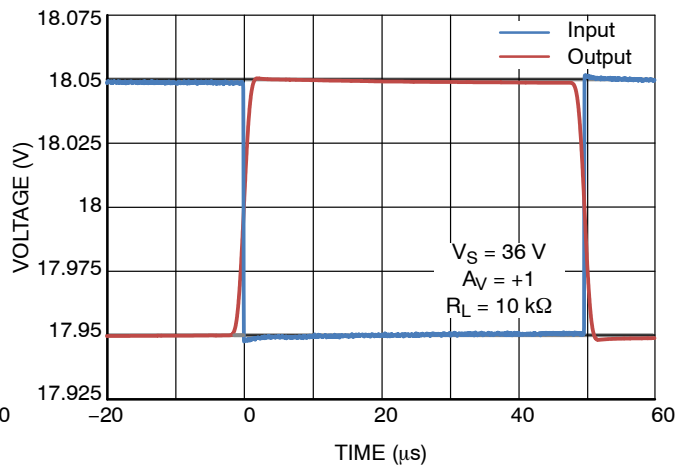
Figure 35. High Level Output vs. Output Current for TLV/NCV272/274



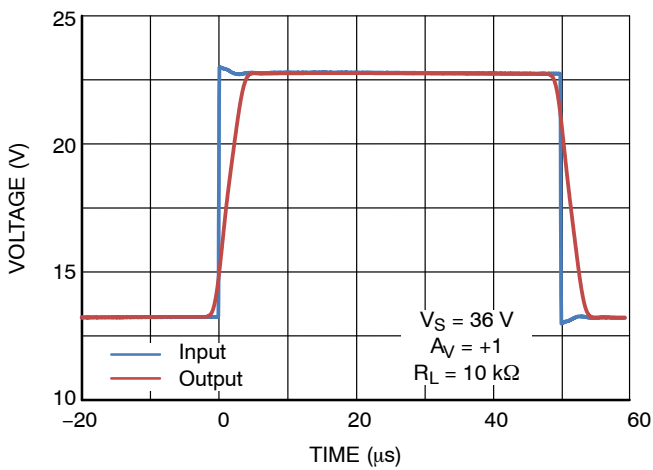
# TLV271, TLV272, NCV272, TLV274, NCV274



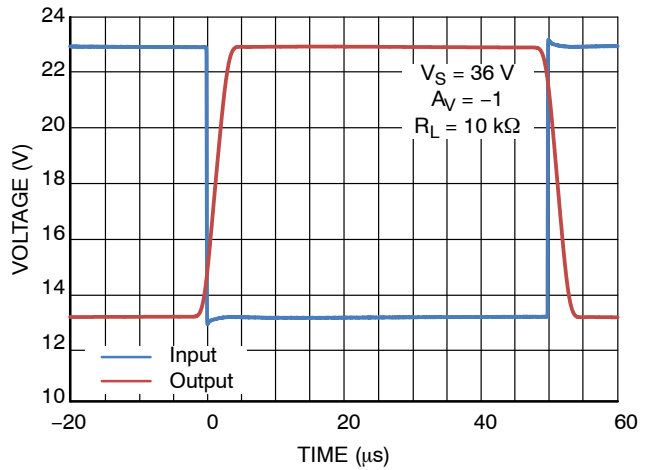
**Figure 36. Non-inverting Small Signal Transient Response for TLV/NCV272/274**



**Figure 37. Inverting Small Signal Transient Response for TLV/NCV272/274**



**Figure 38. Non-inverting Large Signal Transient Response for TLV/NCV272/274**



**Figure 39. Inverting Large Signal Transient Response for TLV/NCV272/274**

APPLICATIONS

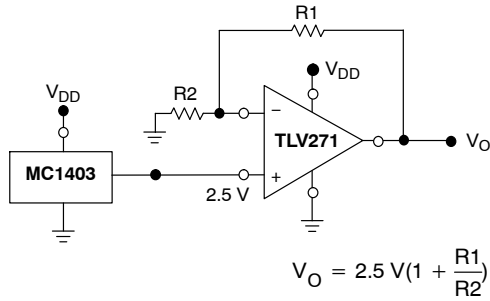


Figure 40. Voltage Reference

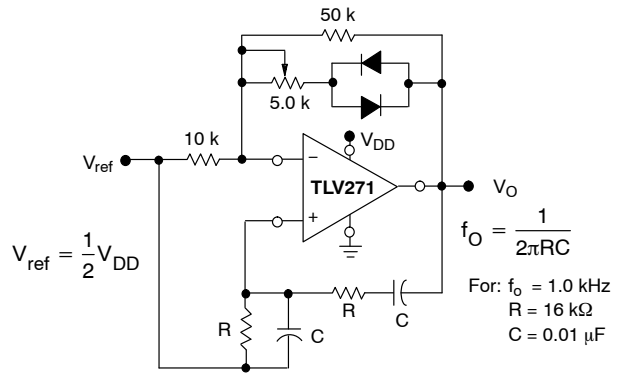


Figure 41. Wien Bridge Oscillator

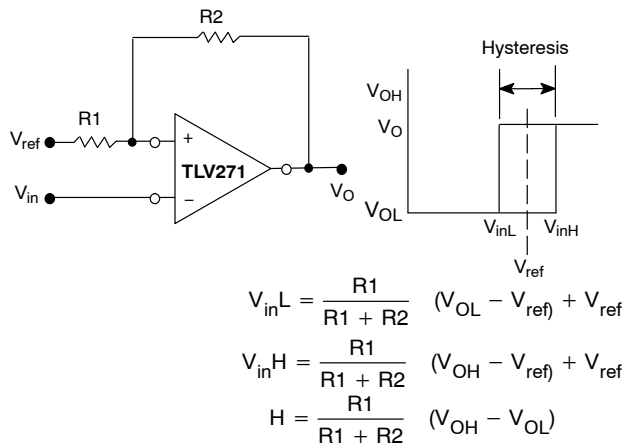
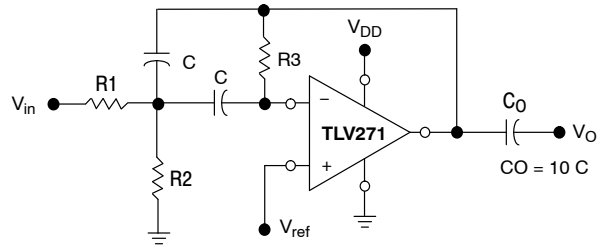


Figure 42. Comparator with Hysteresis



Given:  $f_o$  = center frequency  
 $A(f_o)$  = gain at center frequency

Choose value  $f_o, C$

Then:  $R3 = \frac{Q}{\pi f_o C}$

$$R1 = \frac{R3}{2 A(f_o)}$$

$$R2 = \frac{R1 R3}{4Q^2 R1 - R3}$$

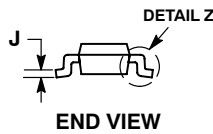
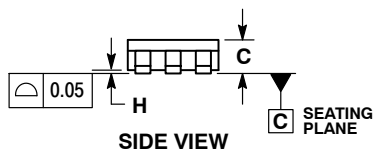
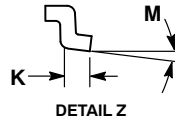
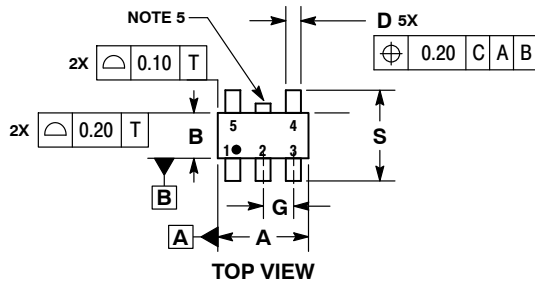
For less than 10% error from operational amplifier,  $((Q_o f_o)/BW) < 0.1$  where  $f_o$  and BW are expressed in Hz. If source impedance varies, filter may be preceded with voltage follower buffer to stabilize filter parameters.

Figure 43. Multiple Feedback Bandpass Filter

# TLV271, TLV272, NCV272, TLV274, NCV274

## PACKAGE DIMENSIONS

### TSOP-5 CASE 483 ISSUE M

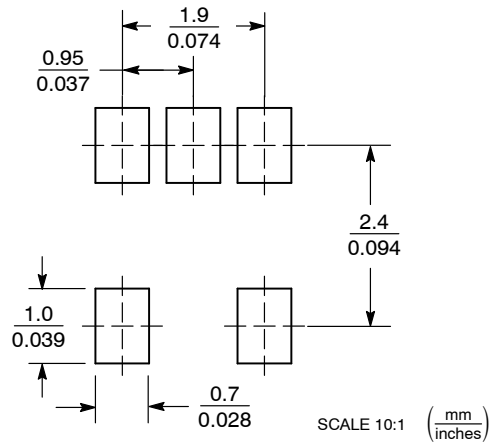


#### NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE. DIMENSION A.
5. OPTIONAL CONSTRUCTION: AN ADDITIONAL TRIMMED LEAD IS ALLOWED IN THIS LOCATION. TRIMMED LEAD NOT TO EXTEND MORE THAN 0.2 FROM BODY.

DIM	MILLIMETERS	
	MIN	MAX
A	2.85	3.15
B	1.35	1.65
C	0.90	1.10
D	0.25	0.50
G	0.95 BSC	
H	0.01	0.10
J	0.10	0.26
K	0.20	0.60
M	0°	10°
S	2.50	3.00

#### SOLDERING FOOTPRINT\*

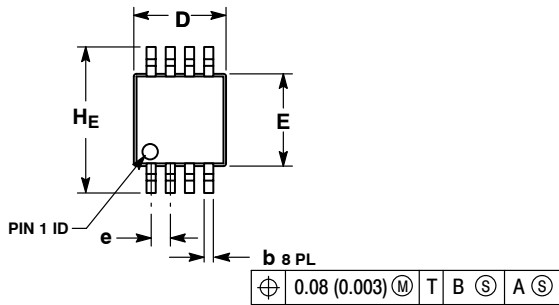


\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# TLV271, TLV272, NCV272, TLV274, NCV274

## PACKAGE DIMENSIONS

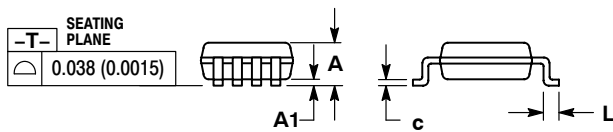
**Micro8™**  
CASE 846A-02  
ISSUE J



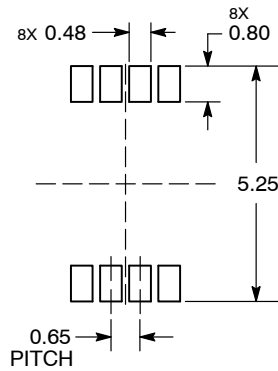
**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. 846A-01 OBSOLETE, NEW STANDARD 846A-02.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	--	--	1.10	--	--	0.043
A1	0.05	0.08	0.15	0.002	0.003	0.006
b	0.25	0.33	0.40	0.010	0.013	0.016
c	0.13	0.18	0.23	0.005	0.007	0.009
D	2.90	3.00	3.10	0.114	0.118	0.122
E	2.90	3.00	3.10	0.114	0.118	0.122
e	0.65 BSC			0.026 BSC		
L	0.40	0.55	0.70	0.016	0.021	0.028
HE	4.75	4.90	5.05	0.187	0.193	0.199



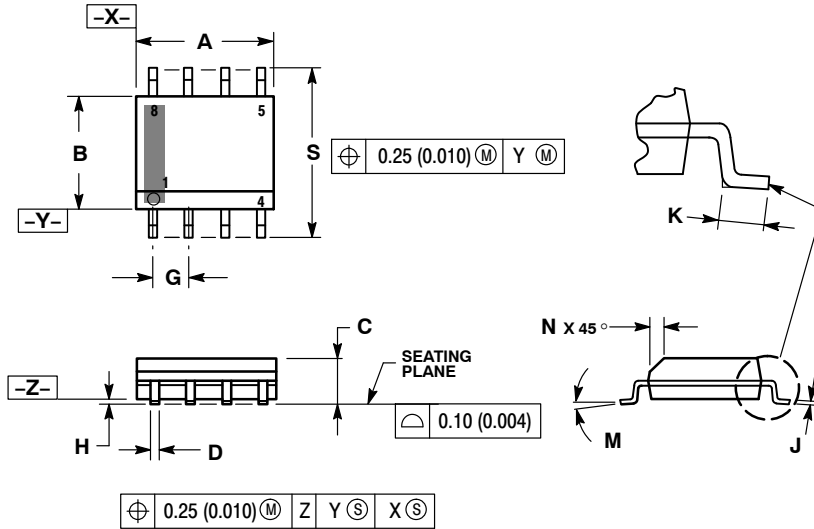
### RECOMMENDED SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

SOIC-8 NB  
CASE 751-07  
ISSUE AK

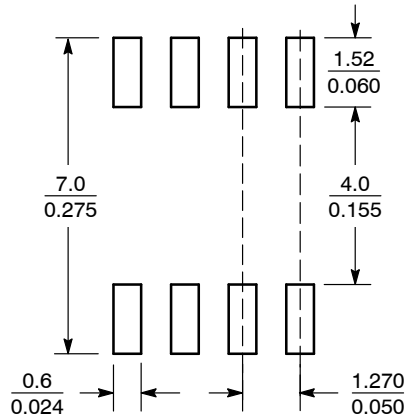


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.80	5.00	0.189	0.197
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27 BSC		0.050 BSC	
H	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
M	0°	8°	0°	8°
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

SOLDERING FOOTPRINT\*



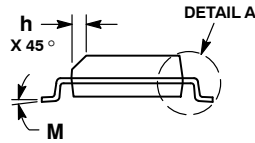
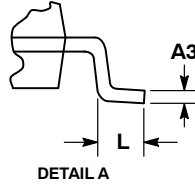
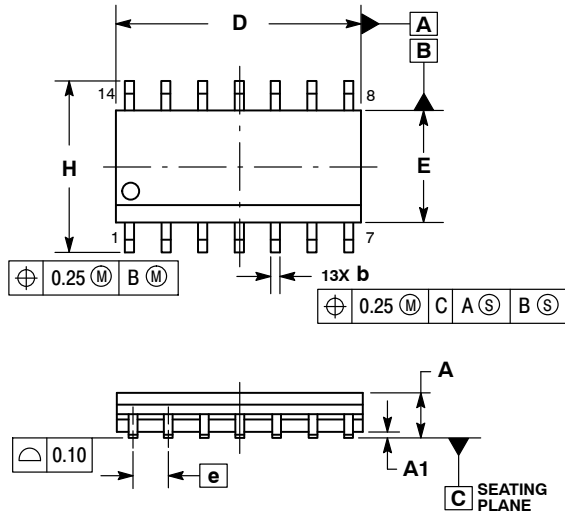
SCALE 6:1  $\left(\frac{\text{mm}}{\text{inches}}\right)$

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# TLV271, TLV272, NCV272, TLV274, NCV274

## PACKAGE DIMENSIONS

SOIC-14 NB  
CASE 751A-03  
ISSUE L

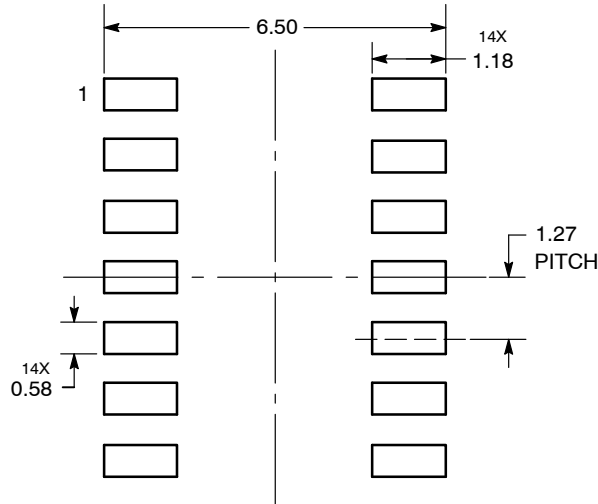


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF AT MAXIMUM MATERIAL CONDITION.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSIONS.
5. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.35	1.75	0.054	0.068
A1	0.10	0.25	0.004	0.010
A3	0.19	0.25	0.008	0.010
b	0.35	0.49	0.014	0.019
D	8.55	8.75	0.337	0.344
E	3.80	4.00	0.150	0.157
e	1.27 BSC		0.050 BSC	
H	5.80	6.20	0.228	0.244
h	0.25	0.50	0.010	0.019
L	0.40	1.25	0.016	0.049
M	0°	7°	0°	7°

### SOLDERING FOOTPRINT\*



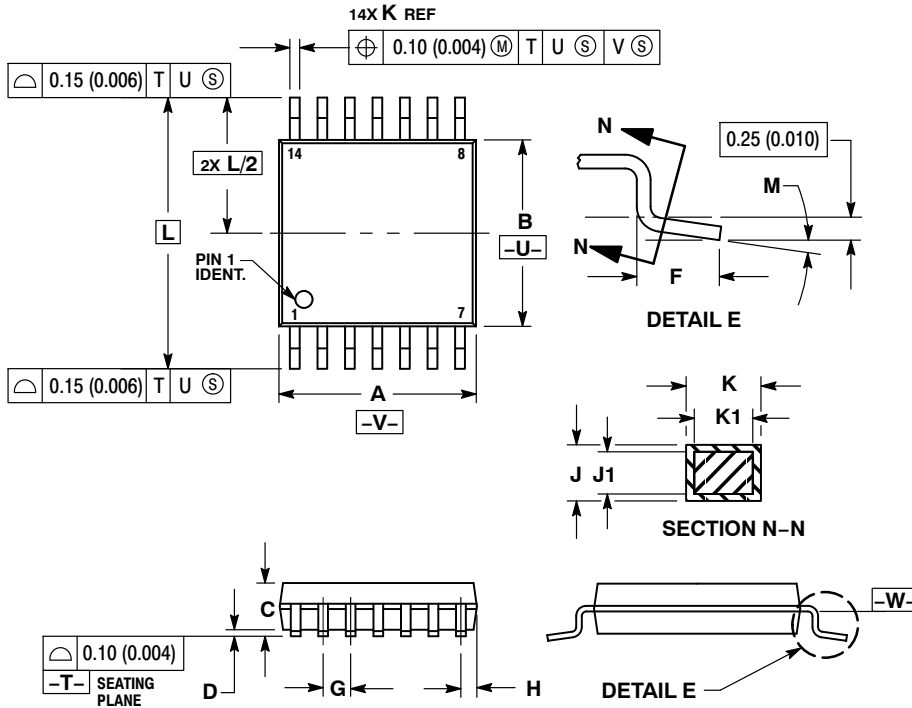
DIMENSIONS: MILLIMETERS

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# TLV271, TLV272, NCV272, TLV274, NCV274

## PACKAGE DIMENSIONS

TSSOP-14  
CASE 948G  
ISSUE C

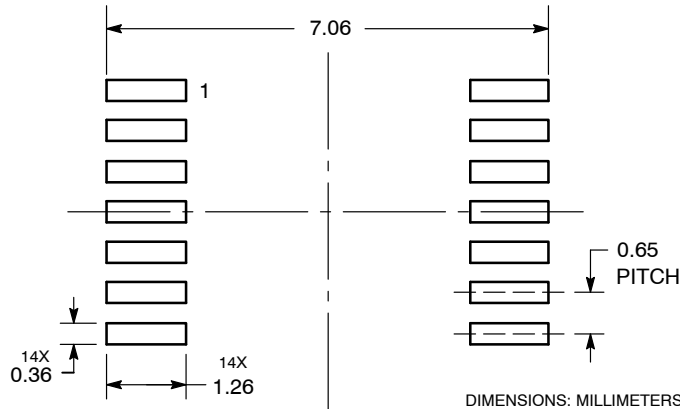


### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.90	5.10	0.193	0.200
B	4.30	4.50	0.169	0.177
C	---	1.20	---	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.50	0.60	0.020	0.024
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0°	8°	0°	8°

### SOLDERING FOOTPRINT



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